## NSN 5961-01-356-4289



Diode Semiconductor Device - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-356-4289 **Inclosure Material:** Ceramic **Overall Length:** Between 0.085 inches and 0.097 inches **Terminal Length:** Between 0.060 inches and 0.064 inches **Overall Diameter:** Between 0.118 inches and 0.127 inches **Function For Which Designed:** Switching **Mounting Method: Terminal Features Provided:** Burn in and gold plated leads and hermetically sealed case and quality assurance level txv **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 300.0 breakdown voltage, dc and 240.0 working peak reverse voltage **Current Rating Per Characteristic:** 40.00 milliamperes source cutoff current preset **Power Rating Per Characteristic:** 12.5 watts small-signal input power, common-collector **Special Features:** Nuclear hardness critical item; junction pattern arrangement: nip **Precious Material And Location:** Terminal surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 2 ferrule Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

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